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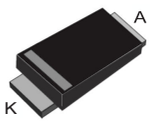
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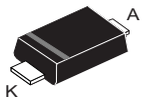
Datasheet

Automotive 100 V - 1 A power Schottky trench rectifier





SOD128Flat



SOD123Flat

Features

- AEC-Q101 qualified
- PPAP capable
- Low forward voltage drop
- Low recovery charges
- Reduces conduction, reverse and switching losses
- 100% Avalanche tested in production
- Operating T_j from -40 °C to +175 °C
- Flat packages
- ECOPACK2 compliant

Applications

- Automotive LED lighting
- Flyback topology
- On-board DC/DC converter
- ECU power supply

Description

This 1 A, 100 V rectifier is based on ST trench technology that achieves the best-in-class V_F/I_R trade-off for a given silicon surface.

Integrated in flat and space-saving packages, this STPST1H100-Y trench, and automotive-graded device is intended to be used in high frequency miniature switched mode power supplies such as in automotive, DC/DC converters or ECU power supply. It is also adapted to freewheeling applications, OR-ring, or reverse polarity protection.

Product label
SUSTAINABLE TECHNOLOGY

Product status link
STPST1H100-Y

Product summary	
$I_{F(AV)}$	1 A
V_{RRM}	100 V
T_j (max.)	175 °C
V_F (typ.)	0.580 V

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1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage (T_j = -40°C to + 175°C)			100	V
$I_{F(AV)}$	Average forward current, δ = 0.5, square wave	SOD123Flat	T_L = 155 °C	1	A
		SOD128Flat	T_L = 155 °C		
I_{FSM}	Surge non repetitive forward current	SOD123Flat	t_p = 10 ms sinusoidal	25	A
		SOD128Flat			
I_{AS}	Single pulse avalanche current(1)	T_j = 25°C, L = 300 µH, V_{DD} = 15 V		2	A
T_{stg}	Storage temperature range			-65 to +175	°C
T_j	Maximum operating junction temperature range(2)			-40 to +175	°C

1. *Please refer to Figure 1 and Figure 2 for the unclamped inductive switching test circuit, and waveform.*
2. *(dP_{tot}/dT_j) < ($1/R_{th(j-a)}$) condition to avoid thermal runaway for a diode on its own heatsink.*

Table 2. Thermal resistance parameter

Symbol	Parameter		Typ. value	Unit
$R_{th(j-l)}$	Junction to lead	SOD123Flat	16	°C/W
		SOD128Flat	15	

For more information, please refer to the following application note:

- AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R(1)	Reverse leakage current	T_j = 125 °C	V_R = 70 V	-	0.15	0.48	mA
		T_j = 25 °C	V_R = 100 V	-		1.7	µA
		T_j = 125 °C		-	0.3	1	mA
V_F(2)	Forward voltage drop	T_j = 25 °C	I_F = 0.5 A	-	0.545	0.610	V
		T_j = 125 °C		-	0.480	0.540	
		T_j = 25 °C	I_F = 1 A	-	0.650	0.725	
		T_j = 125 °C		-	0.580	0.635	

1. *Pulse test: t_p = 5 ms, δ < 2%*
2. *Pulse test: t_p = 380 µs, δ < 2%*

To evaluate the conduction losses, use the following equation:

$P = 0.445 \times I_{F(AV)} + 0.190 \times I_F{}^2{}_{(RMS)}$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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Figure 1. Current and voltage waveforms for avalanche energy test across D.U.T (device under test)

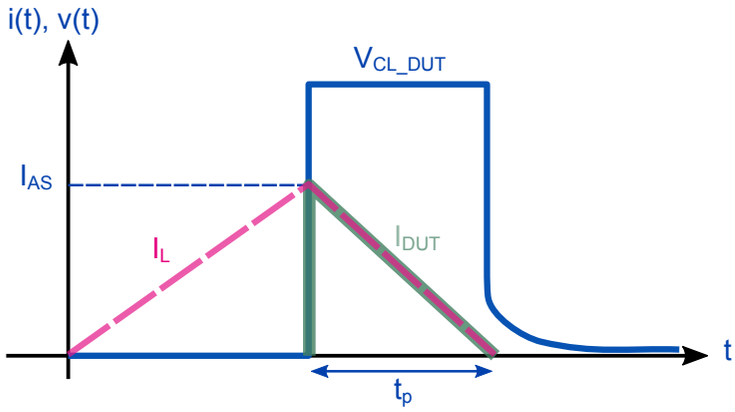
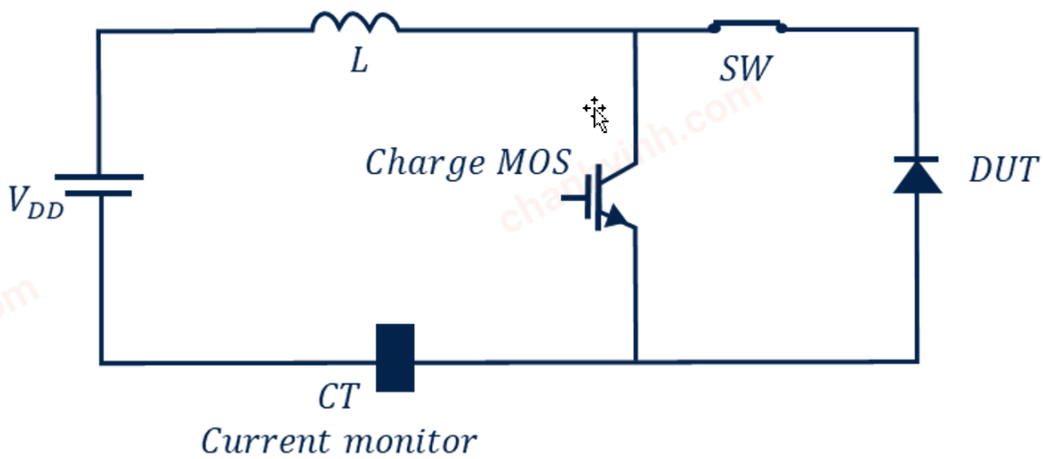


Figure 2. Unclamped Inductive Switching Test circuit



$$E_{AS} = \frac{1}{2} \times L \times {I_{AS}}^2 \times \left(\frac{V_{CLDUT}}{V_{CLDUT} - V_{DD}} \right) \cong \frac{1}{2} \times L \times {I_{AS}}^2$$

$$t_p = \left(\frac{L \times I_{AS}}{V_{CLDUT} - V_{DD}} \right)$$

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1.1 Characteristics (curves)

Figure 3. Average forward current versus lead temperature (δ = 0.5)

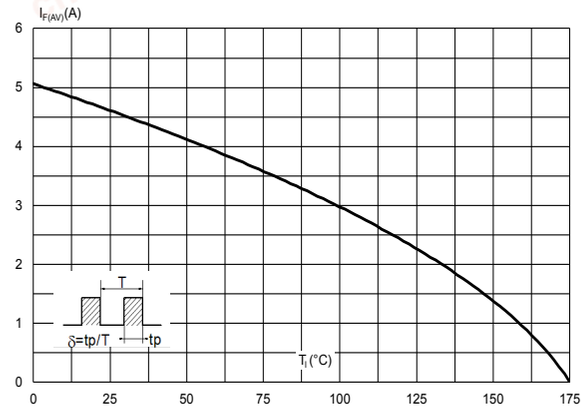


Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration (SOD123Flat)

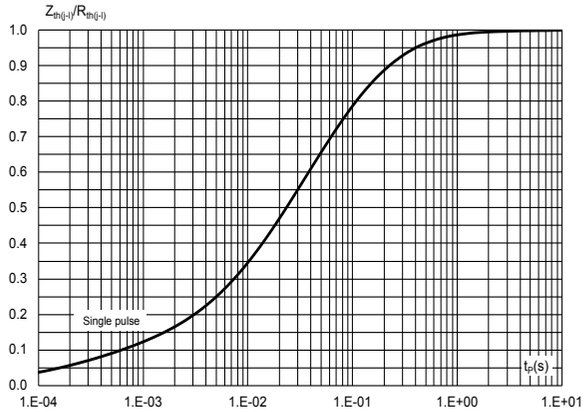


Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration (SOD128Flat)

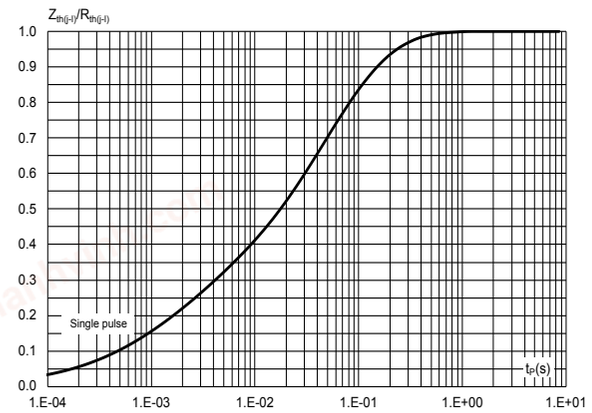


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

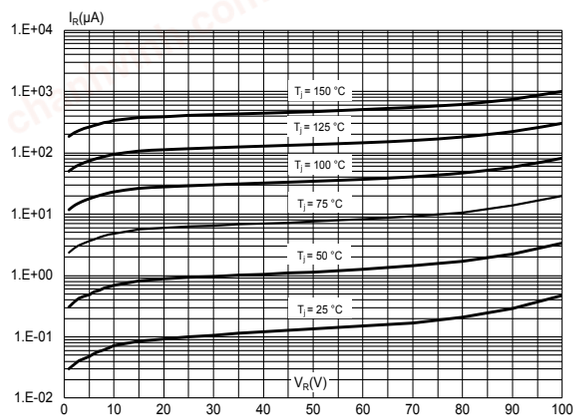


Figure 7. Junction capacitance versus reverse voltage applied (typical values)

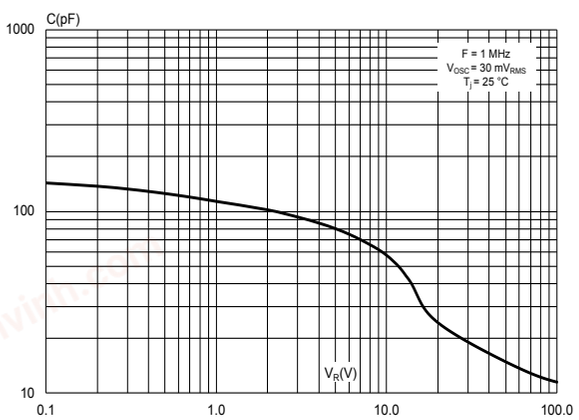
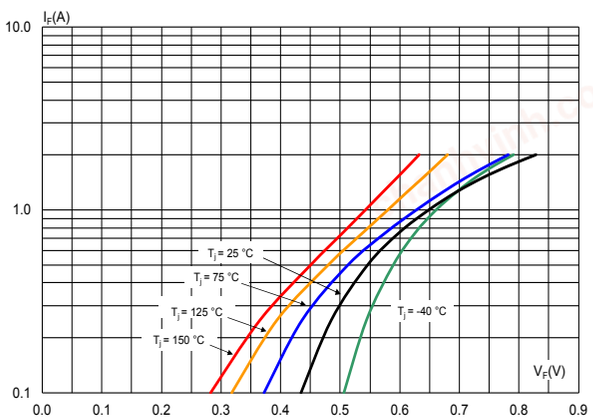


Figure 8. Forward voltage drop versus forward current (typical values)



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Figure 9. Thermal resistance junction to ambient versus copper surface under each lead (typical values, epoxy printed board FR4, e_{Cu}= 70 µm)

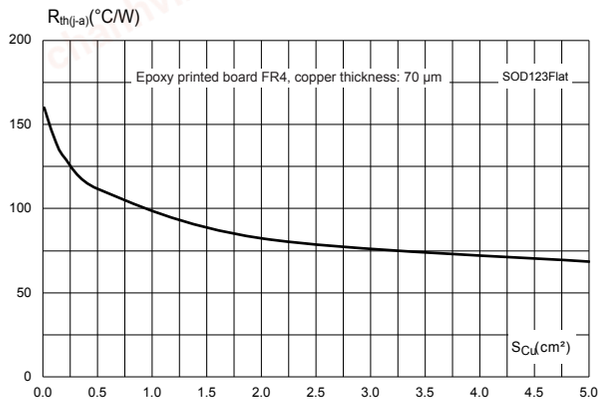
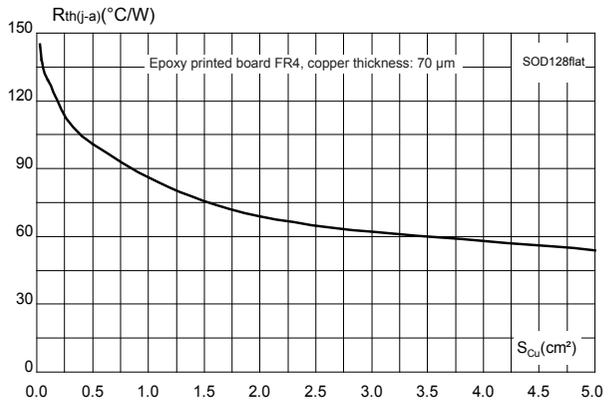


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values, epoxy printed board FR4, e_{Cu}= 70 µm)



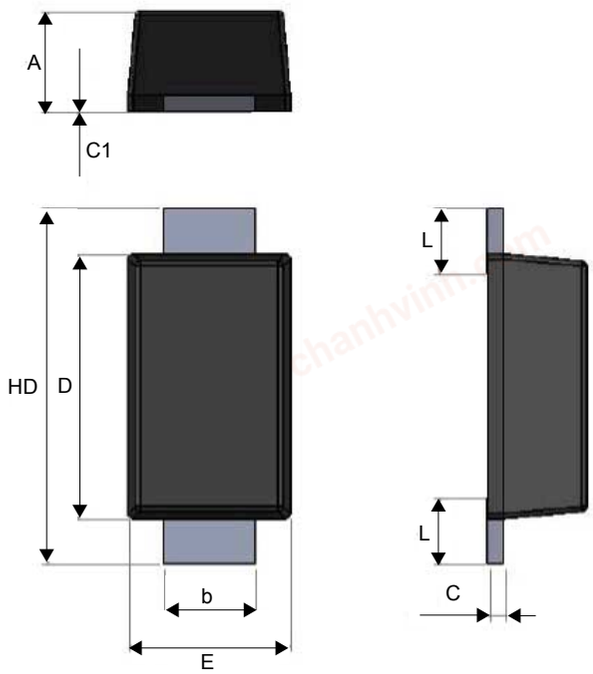
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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SOD123Flat package information

Figure 11. SOD123Flat package outline



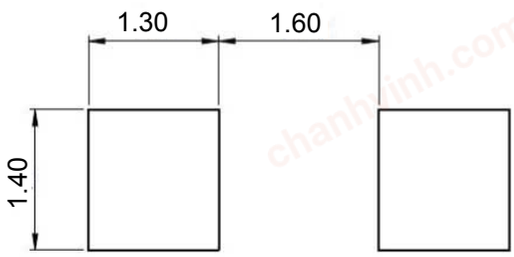
Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

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Table 4. **SOD123Flat package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.86	0.98	1.10	0.034	0.038	0.043
b	0.80	0.90	1.00	0.031	0.035	0.039
c	0.08	0.15	0.25	0.003	0.006	0.009
c1	0.00		0.10	0.000		0.004
D	2.50	2.60	2.70	0.098	0.102	0.106
E	1.50	1.60	1.80	0.059	0.063	0.070
HD	3.30	3.50	3.70	0.130	0.137	0.146
L	0.45	0.65	0.85	0.018	0.025	0.033

Figure 12. **SOD123Flat footprint dimensions (mm)**



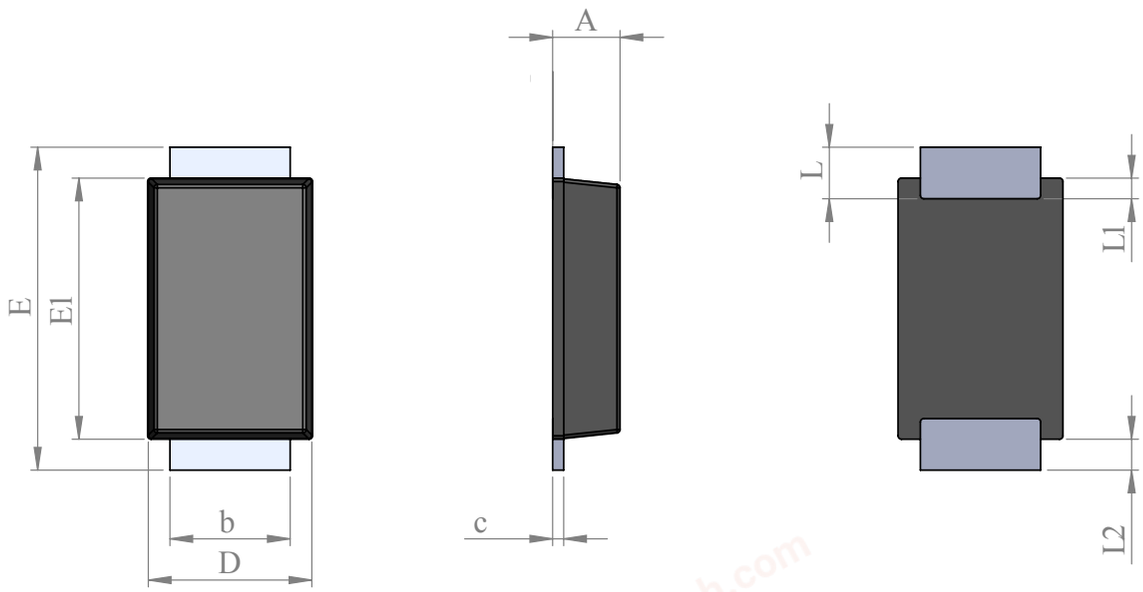
Note: For package and tape orientation, reel and inner box dimensions and tape outline please check TN1173.

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2.2 SOD128Flat package information

- Lead-free package

Figure 13. SOD128Flat package outline



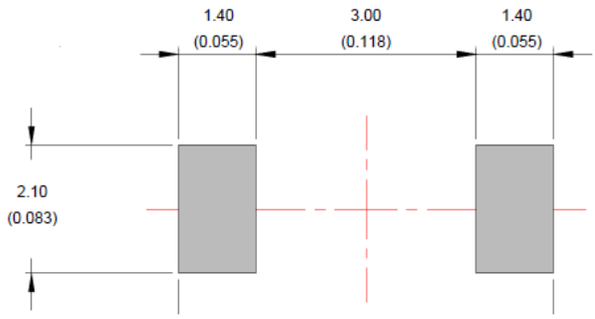
Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 5. SOD128Flat package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.93	1.03	0.037	0.041
b	1.69	1.81	0.067	0.071
c	0.10	0.22	0.004	0.009
D	2.30	2.50	0.091	0.098
E	4.60	4.80	0.181	0.189
E1	3.70	3.90	0.146	0.154
L	0.55	0.85	0.026	0.033
L1	0.30 typ.		0.012 typ.	
L2	0.45 typ.		0.018 typ.	

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Figure 14. **SOD128Flat footprint in mm (inches)**



Note: For package and tape orientation, reel and inner box dimensions and tape outline please check TN1173.

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3 Ordering information

Table 6. **Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPST1H100ZFY	TY1	SOD123 Flat	12.5 mg	3000	Tape and reel
STPST1H100AFY	T1H1Y	SOD128Flat	26.4 mg	3000	

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Revision history

Table 7. **Document revision history**

Date	Revision	Changes
16-Dec-2022	1	Initial release.
26-May-2023	2	Updated Figure 13.
24-Jul-2023	3	Updated *Features*.

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